L Number 1		Search Text ("5804506").PN.	DB USPAT; US-PGPUB;	Time stamp 2002/12/05 11:50
2	2	("5972769").PN.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/12/05 10:56
3	2	("6376303").PN.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/12/05 10:57
4	2	("5827783").PN.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/12/05 13:11
5	5502	((257/68) or (257/71) or (257/277) or (257/296) or (257/298) or (257/300) or (257/303) or (257/306) or (257/516) or (257/532) or (257/906)).CCLS.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/12/05 13:12
6	13	(((257/68) or (257/71) or (257/277) or (257/296) or (257/298) or (257/300) or (257/303) or (257/306) or (257/516) or (257/532) or (257/906)).CCLS.) and	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/12/05 13:13
- 0)	0	corrugat\$3 near15 (capacitor or capacitance) and memory.ti,ab. ("(boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat\$3 or rippl\$3)").PN.	IBM_TDB  USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/02/08 13:58
-	77	(boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat\$3 or rippl\$3)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/02/08 14:10
- '	0	((boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat\$3 or rippl\$3)) and (rippl\$3 or	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/02/08 14:00
-	3	corrugat\$3) near12 (capacitor adj2 wall) ((boro-silicate adj glass or bpsg or germanium adj boro-silicate glass or ge-bpsg) and capacitor and dram and (corrugat\$3 or rippl\$3)) and (rippl\$3 or corrugat\$3) near12 (capacitor adj2 (plate	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:00
-	43	or wall)) (((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same capacitor and (memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:14
-	43	adj3 (cell or device)) and dram ((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same capacitor) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14:14

-	0	<pre>((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same (rippl\$3 or corrugat\$3) same capacitor) and (memory adj3 (cell or</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 1	4:15
_	41	<pre>device)) and dram  ((((borosilicate or boro-silicate) adj  glass or bpsg or germanium adj  (borosilicate or boro-silicate) adj glass  or ge-bpsg) near12 (stack\$2 or  alternat\$3)) same capacitor) and (ripp1\$3  or stack\$2) and (memory adj3 (cell or  device)) and dram</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 1	4:16
-	2	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) nearl2 (stack\$2 or alternat\$3)) same capacitor) and ((rippl\$3 or stack\$2) nearl2 (capacitor adj2 (plate or wall))) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 1	4:19
-		((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) nearl2 (stack\$2 or alternat\$3)) same capacitor) and ((rippl\$3 or corrugat\$2) nearl2 (capacitor adj2 (plate or wall))) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 1	4:20
-	0	((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same capacitor) and ((rippl\$3 or corrugat\$2) near12 (plate or wall)) and (memory adj3 (cell or device)) and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 1	4:20
-	0	<pre>((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same capacitor) and ((rippl\$3 or corrugat\$2) near12 (plate or wall)) and</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 1	4:21
-	0	dram ((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same capacitor) and ((rippl\$3 or corrugat\$2) near12 (plate or wall))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14	4:21
-	0	<pre>((((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (stack\$2 or alternat\$3)) same capacitor) and ((rippl\$3 or corrugat\$2))</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 14	4:22
-	2	(((borosilicate or boro-silicate) adj glass or bpsg or germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 capacitor) and ((rippl\$3 or corrugat\$2) near12 capacitor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/08 15	5:32
-	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) nearl2 (borosilicate or boro-silicate) adj glass) nearl2 (capacitance or capacitor or stacked or stacking)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08 15	5:35

	r10	//www.river.ali /hawaailiaaka ay	HCDAT.	2002/02/09	15.27
_	512	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) near12 (borosilicate or boro-silicate) adj glass or bpsg) near12 (capacitance or capacitor or stacked or stacking or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/08	15:37
-	51	alternate or alternating or alternatingly) ((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass	USPAT; US-PGPUB; EPO; JPO;	2002/02/08	15:37
-	646	or bpsg) near12 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) ((germanium adj (borosilicate or	DERWENT; IBM_TDB USPAT;	2002/02/08	15:37
		boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) with (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB		
-	51	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08	15:37
_	38	alternating or alternatingly) ((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08	15:38
-	30	alternating or alternatingly) and dram ((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or	USPAT	2002/02/08	15:46
-	0	alternating or alternatingly) and dram ((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and	USPAT	2002/02/08	15:40
-	0	corrugat\$3 ((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08	15:40
_	0	corrugat\$3 ((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and (rippl\$3 or corrugat\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08	15:41
-	0	((germanium adj (borosilicate or boro-silicate) adj glass or ge-bpsg) with (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram and (ripp1\$3 or corrugat\$3 or standing adj	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/08	15:42
-	30	<pre>wav\$3) (ge-bpsg and (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and dram</pre>	USPAT	2002/02/08	15:47

-	0	(ge-bpsg and (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and (rippl\$3 or corrugat\$3) and dram	USPAT	2002/02/08 1	5:48
-	0	(ge-bpsg and (borosilicate or boro-silicate) adj glass or bpsg) near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly) and (rippl\$3 or corrugat\$3)	USPAT	2002/02/08 1	.5:49
-	0	(ge-bpsg near10 (capacitance or capacitor or stacked or stacking or alternate or alternating or alternatingly)) and (rippl\$3 or corrugat\$3)	USPAT	2002/02/08 1	5:50
-	0	(ge-bpsg or germanium-boro-phospho adj silicate adj glass or germanium adj boro-phospho adj silicate adj glass or germanium-boro-phospho-silicate adj glass or germanium adj boro adj phospho adj silicate adj glass) same (stacked or stacking or alternating or alternate or alternately or multi-layer or multi adj layer or laminat\$3)	USPAT	2002/02/08 1	5:56
. <del>-</del>		ge-bpsg or germanium-boro-phospho adj silicate adj glass or germanium adj boro-phospho adj silicate adj glass or germanium-boro-phospho-silicate adj glass or germanium adj boro adj phospho adj silicate adj glass or ge-bpsg	USPAT	2002/02/08 1	
_		5648175.pn. (("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.	USPAT USPAT	2002/02/09 1 2002/02/09 1	
-	0	((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) and corrugat\$3 and capacit\$3 and bpsg and ge-bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 1	0:14
-	0	(("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) and capacit\$3 and bpsq and ge-bpsq	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 1	0:14
-	118	((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 1	0:18
-		((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3) and "L14"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 1	0:17
-	0	((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3) and "L14"	USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 1	0:17

-	131	<pre>((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or (((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3))</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:18
-	35	(((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("587987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or ((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3))) and ((increas\$3 near5 capacitance) near5 etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:21
-	6	(((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or ((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3))) and ((increas\$3 near5 capacitance) near5 etch\$3)) and bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:4:
-	2	(((((("5061650") or ("5240871") or ("5300801") or ("5466627") or ("5637523") or ("5656536") or ("5827783") or ("5843822") or ("5879987") or ("6025225") or ("6027970") or ("6028763") or ("6060355") or ("6074926")).PN.) or ((increase near5 capacitance) near5 surface) near5 (rough\$5 or etch\$3))) and ((increas\$3 near5 capacitance) near5 etch\$3)) and bpsg) and germanium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 10:42
-	166	different adj etch\$3 adj2 rates and bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 10:42
-	0	(different adj etch\$3 adj2 rates near5 bpsg) near5 capacitance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 10:43
-	11	different adj etch\$3 adj2 rates near5 bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 11:09
-	507	etch\$3 adj rate same bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 11:09
-	318	etch\$3 adj rate with bpsg	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09 11:09
-	1	etch\$3 adj rate with (bpsg and (ge-bpsg or germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09 16:42

- 3	5827783.pn.	USPAT; US-PGPUB; EPO; JPO;	2002/02/09	17:35
- 68	(bst same capacitor same dielectric) and	DERWENT; IBM_TDB USPAT;	2002/02/09	17:36
	memory adj device.ti,ab.	US-PGPUB; EPO; JPO; DERWENT; IBM TDB		
- 25	(bst near6 capacitor near6 dielectric) and memory adj device.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/02/09	17:55
- 2	((si-ge or silicon-germanium) same capacitor same dielectric) and memory adj device.ti,ab.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09	22:09
- 2	5930106.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09	18:01
- 4791	((257/68) or (257/71) or (257/277) or (257/296) or (257/298) or (257/300) or (257/303) or (257/306) or (257/516) or (257/532) or (257/906)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09	22:10
- 3	((("257/68") or ("257/71") or ("257/277") or ("257/296") or ("257/298") or ("257/300") or ("257/303") or ("257/306") or ("257/516") or ("257/532") or ("257/906")).CCLS.) and bpsg and germanium and capacitor and memory adj2 device.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/02/09	22:11
- 3	5827783.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09	22:12
- 3	5804506.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09	22:13
- 3	5889696.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/09	22:13
- 2	5889696.pn.	USPAT; DERWENT	2002/02/10	09:09
- 2	5930106.pn.	USPAT; DERWENT	2002/02/10	09:10
- 0	(323/539).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/08	16:56
- 1364	(band adj gap or bandgap) adj reference near5 voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/08	16:57
- 275	(bandgap) adj reference near5 voltage and bipolar adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/08	16:58

155 (327/539).CCLS.

USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM\_TDB

2002/05/08 16:58